Bose-Einstein condensation in tight-binding bands

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(9 July 2005)

We present a theoretical study of condensation of bosons in tight binding bands corresponding to simple cubic, body centered cubic, and face centered cubic lattices. We have analyzed non-interacting bosons, weakly interacting bosons using Bogoliubov method, and strongly interacting bosons through a renormalized Hamiltonian approach valid for number of bosons per site less than or equal to unity. In all the cases studied, we not that bosons in a body centered cubic lattice has the highest Bose condensation temperature. The growth of condensate fraction of non-interacting bosons is found to be very close to that of free bosons. The interaction partially depletes the condensate at zero temperature and close to it, while enhancing it beyond this range below the Bose-Einstein condensation temperature. Strong interaction enhances the boson elective mass as the band-lling is increased and eventually localizes them to form a Bose-Mott-Hubbard insulator for integer lling.

PACS numbers: 03.75 Lm, 03.75 Nt, 03.75 Hh, 67.40.-w

I. IN TRODUCTION

In a m any boson system, when the therm alde-B roglie wavelength of a particle becomes comparable to the interparticle separation, a condensation in momentum space occurs at a nite tem perature and a macroscopic number of particles occupy the lowest single particle energy level and enter in to a phase locked state. This phenomenon predicted by Einstein by applying Bose statistics² to a three dim ensional hom ogeneous system of non-interacting atoms in the therm odynamic limit is well known as the Bose-Einstein condensation. Though it took seventy years to eventually observe Bose-E in stein condensation 3 in metastable, inhomogeneous, nite, and three dim ensional Bose atom vapors, progress ever since has been trem endous. Extensive investigations of various aspects of the condensate, a macroscopic quantum coherent state of atom s, is now a rapidly expanding eld of research $^{7\{11}$.

One of the interesting recent developments in this eld is the observation 12, by G reiner and collaborators, of a transition between super uid and M ott insulating phases of bosons in an optical lattice. Experimentalists have explored this super uid-M ott transition and the excitation spectra in the super uid12;13 and M ott insulating phases¹². In these experiments, the condensate is adiabatically transferred to a simple cubic optical lattice produced by counter propagating laser beam s. By changing the characteristics of the laser beam s, it has been possible to achieve great control over t=U, where t is the inter-site hopping energy and U the on-site boson-boson interaction energy. It has been shown that bosons in optical lattices can be adequately modeled employing a clean Bose- ${
m H}\,{
m ubbard}\,{
m m}\,{
m odel}^{14}$. That a band-width controlled transition from a super uid state to a Bose-Mott-Hubbard (BMH) insulating state is possible at a critical value of t=U for integer num ber of bosons per site was predicted in

theoretical studies 14 19 on Bose-Hubbard model. In the BMH insulator, the bosons are site localized and the single particle excitation spectrum acquires a gap. Recently, super uid to Mott insulator transition was observed in nite one-dimensional optical lattices as well.

The experim ental realization of bosons in optical lattices provides a microscopic laboratory for the exploration of collective behavior of quantum many particle systems in narrow energy bands with great control on t, U, and the number of boson per site (n). There is already theoretical studies^{21;22} on the possibility of creating di erent types of two dim ensional lattices (triangular, square, hexagonal, for example). It has been proposed²³ recently that trim erized optical Kagome lattice can be achieved experim entally and that a super uid-M ott transition at fractional lling is possible for bosons in this lattice. It is reasonable to expect that three and two dim ensional optical lattices of di erent sym m etries will be created in near future. M any experim ental groups have produced three dim ensional optical lattices and experim ental studies of B ose condensates in these lattices will surely receive increasing attention in the coming years. Motivated by such possibilities, we present a theoretical study of Bose-Einstein condensation in tight binding bands corresponding to simple cubic (sc), body centered cubic (bcc), and face centered cubic (fcc) lattices. We have analyzed non-interacting, weakly interacting, and strongly interacting bosons. The weakly interacting bosons were analyzed using a Bogoliubov type theory²⁴. For the strongly interacting bosons, we use a renorm alized Hamiltonian valid for n 1 obtained by projecting out on-site multiple occupancies. This analysis is presented in the next section and the conclusions are given in Sec. III.

II. BOSE CONDENSATION IN TIGHT BINDING BANDS

A . N on-interacting bosons

In this section we discuss the sim plest of the three cases studied. The Ham iltonian of the non-interacting bosons in a tight-binding energy band is:

$$H = {\begin{array}{*{20}{c}} X \\ {}_{k} {\end{array}}} [(k) {)} {}_{k} {\phantom{*{20}{c}}} {\phantom{*{20$$

where (k) is the band-structure corresponding to sc, bcc, and fcc lattices, the chem ical potential, and c_k^y is the boson creation operator. Con ning to nearest neighbor W annier functions overlaps, these band structures when lattice constant is set to unity are,

$$\sum_{SC} (k_{x}; k_{y}; k_{z}) = 2t \cos(k);$$

$$= x$$

$$\sum_{DCC} (k_{x}; k_{y}; k_{z}) = 8t \cos(k);$$

$$= x$$

$$(2)$$

and,

$$f_{\text{cc}}(k_x; k_y; k_z) = 2t \sum_{=x; 6}^{X^z} \sum_{=x}^{X^z} \frac{k}{2} \cos \frac{k}{2} ;$$
(3)

where t is the nearest neighbor boson hopping energy. The condensation temperature (T_B) for bosons in these bands can be calculated from the boson number equation:

$$n = \frac{1}{N_{x}N_{y}N_{z}} X_{k_{x} k_{y} k_{z}} \frac{1}{e^{[(k_{x};k_{y};k_{z})]=k_{B}T} 1}; (4)$$

where $N_s = N_x N_y N_z$ is the total number of lattice sites, k_{B} the B lotzm ann constant, and T the temperature. At high tem perature, the chem ical potential is large and negative. As the temperature comes down, the chemical potential raises gradually to eventually hit the bottom of the band. Below this temperature there is macroscopic occupation of the band bottom and we have a Bose condensate. On further reduction of tem perature, the chem ical potential is pinned to the bottom of the band and bosons are progressively transferred from excited states in to the condensate. All the particles are in the condensate at absolute zero tem perature. Fixing the chemical potential at the bottom of the band the solution of the number equation gives the Bose condensation temperature (T_B). For $T > T_B$ a lower value of satis es the num ber equation, while for $T < T_B$ the RHS of Eq. (4) is less than the number of bosons (n), the di erence being the number of condensate particles (n_0) . We determ ined T_B and n_0 for dierent lattices as a function of lling and

tem perature. Results of these calculations are shown in Figs. 1-5. We nd that for bosons in the tight binding band corresponding to the bcc lattice has the highest Bose condensation temperature. Comparing the single boson Density Of States (DOS), we nd that the band structure with smallest DOS near the bottom of the band has the highest T_B . The physical reason behind it is that, as the tem perature is lowered from above the Bose condensation temperature, the bosons are transferred from the high energy states to the low energy states following the Bose distribution function. To accomm odate these bosons the chemical potential would touch the bottom of the boson band at a higher tem perature for a system with smaller DOS near the bottom of the band compared to a system which has larger DOS there. Consequently the Bose condensation temperature for the former system would be higher than that for the latter. The growth of the condensate fraction for di erent lattices is shown in Figs. (1)-(3), and in Fig (4) we have compared condensate fraction growth for dierent lattices. Also shown by dotted lines is the condensate fraction for free bosons and they are found to be rather close. The variation of $T_{\rm B}$ with n is shown in Fig. (5) which shows an initial fast growth and a monotonic increase for higher values of n.

B.W eakly interacting bosons

To study Bose condensation of weakly interacting Bosons in tight binding bands, we employ the following Hamiltonian:

$$H = \begin{bmatrix} X \\ [(k)] \end{bmatrix} c_{k}^{y} c_{k}$$

$$+ \frac{U}{2N_{s}} \begin{bmatrix} X & X & X \\ k & k^{0} & q \end{bmatrix} c_{k+q}^{y} c_{k^{0}q}^{y} c_{k} c_{$$

Here (k) is the boson band structure, potential, c_k^V the boson creation operator, U the bosonboson repulsive interaction energy taken to be a constant for sim plicity, and N_s the number of lattice sites. In this section, we will deal with a range of U such that U < 2W where W is the half-band-width. Our aim is to get a boson number equation in terms of (k), U, , and temperature. One can then calculate the condensate fraction and the transition temperature. To this end we follow Bogoliubov theory²⁴. In this theory, one makes an assumption that the ground state of interacting bosons is a Bose condensate. Since the lowest single particle state (which is k = 0 in our case of simple tight binding bands) has macroscopic occupation (say N $_0$), we have < $c_0^y c_0 >$ < $c_0 c_0^y >$. Then the the operators c_0^y and c_0 can be treated as $\underset{p}{\text{com}} p \text{ lex num bers}$ and one gets < c_0^y > = < c_0 > = $p \text{ } \frac{1}{N_0}$. This $\underset{p}{\text{com}} - \frac{1}{N_0}$ plex number substitution has been recently shown 25 to be justiled. Clearly we have a two-uid system consisting of two subsystems of condensed and non-condensed

$$H_{BMF} = E_0 + \frac{X^0}{k} \frac{[(k) + U n_0]}{2} (c_k^y c_k + c_k^y c_k)$$

$$+ \frac{U n_0}{2} \frac{X^0}{k} (c_k^y c_k^y + c_k c_k); \qquad (6)$$

where E₀ U $n_0N_0=2$ and (k) (k) 0. As mentioned earlier our aim is to get an equation for number of particles. This can be obtained from the G reen's function²⁶ G (k;!) << c_k ; c_k^V >>! using the relation:

$$n_k = \lim_{\substack{! \ 0}} [G(k;!+i)] G(k;! i)]f(!)d!$$
:

(7)

where $f(!) = 1 = \exp(! = k_B T)$ 1]. The H eisenberg equation of motion for G (k;!) is:

$$! G (k;!) = [c_k; c_t^{y}] + \langle c_k; H]; c_t^{y} >> !;$$
 (8)

where H is the H am iltonian of the system . U sing H $_{\text{B M F}}$, we obtain:

$$! G (k;!) = 1 + [(k) + U n_0]G (k;!) + U n_0F (k;!); (9)$$

and the G reen's function to which G (k;!) is coupled F (k;!) << c_k^y ; c_k^y >>! obeys the equation of motion:

$$!F(k;!) = [(k) + Un_0]F(k;!) Un_0G(k;!)$$
: (10)

Solving the above two equations one obtains:

G (k;!) =
$$\frac{! + (k) + U n_0}{2E (k)}$$
$$\frac{1}{! + E (k)} \frac{1}{! E (k)} : (11)$$

where the Bogoliubov quasiparticle energy E $_{\mbox{\scriptsize k}}\,$ is:

$$E(k) = p^{\frac{2}{(k) + 2U n_0(k)}}$$
: (12)

Note that for the tight binding band dispersions used, E(k) is linear in k in the long wave-length limit. Now,

the number of particles per site (n) is readily obtained using Eqs. (7) and (11) to be:

$$n = n_{0} + \frac{1}{2N_{s}} X^{0} \qquad 1 + \frac{(k) + U n_{0}}{E_{k}} \frac{1}{e^{E(k) = k_{B}T}} 1$$

$$+ \frac{1}{2N_{s}} X^{0} \qquad 1 \qquad \frac{(k) + U n_{0}}{E_{k}} \frac{1}{e^{E(k) = k_{B}T}} : (13)$$

It is useful to look at some lim its of the above equation. When U=0 and T=0, we have $n_0=n$ which means that all the particles are in the condensate at absolute zero in the non-interacting lim it. When U=0 and $T\notin 0$, on obtains:

$$n_0 = n - \frac{1}{N_s} \frac{X^0}{e^{\frac{(k)}{k_B T}}} :$$
 (14)

The second term on the RHS of the above equation is the thermal depletion of the condensate. Further, when U \in 0 and T = 0, we get:

$$n_0 = n - \frac{1}{N_s} X^0 - \frac{(k) + U n_0 - E (k)}{2E (k)}$$
; (15)

in which second term on the RHS is the interaction induced depletion of the condensate. The interaction has twin e ects of leading to a modi ed excitation spectrum and to a partial depletion of the condensate. The gap-less and linear long-wavelength excitation spectrum is consistent with experim entalm easurem ents¹² on interacting bosons in their bose-condensed state in optical lattices. In Fig. (6), we have shown the numerical solution of Eq. (13) for bcc, fcc and sc lattices. The condensate fraction $(n_0=n)$ is seen to be gradually suppressed with increasing U=W . Note also that at U=0, all the particles are in the condensate. Finally, we consider the case: U 6 0 and T $\, \in \,$ 0. In Fig. (7), we have displayed the variation of the condensate fraction as a function of temperature for various values of U=W. The interaction partially depletes the condensate at zero tem perature and close to it, while enhancing it beyond this range below the Bose-Einstein condensation temperature. We have not plotted these curves all the way to TB since the Bogoliubov approxim ation breaks down close to T_{B} . The variation of T_{B} with n is same as in the case of non-interacting bosons as can be seen by setting $n_0 = 0$ in Eq. (13). At very low tem perature, therm aldepletion is negligible and correlation induced depletion causes a reduction of no with increasing U. At higher tem peratures when thermaldepletion is important, U plays another role. The energies of the excited states shift to larger values with increasing U, consequently the population in the excited states decreases and an enhancem ent of no occurs with increasing

The analysis presented in this section is reasonable provided the elect of interaction is perturbative. When the

interaction strength increases, there is a possibility for a correlation induced localization transition for interacting bosons in a narrow band. In the next section, we analyze this strongly interacting bosons case.

C . Strongly interacting bosons

We rst write the H am iltonian, Eq. (5), in real space. Then we have:

$$H = \sum_{ij}^{X} [t \quad _{ij}]c_{i}^{y}c_{j} + \frac{U}{2} \quad n_{i}(n_{i} \quad 1); \quad (16)$$

where $n_i = c_i^y c_i$. For simplicity, let us con ne to the case of n 1. The e ect of increasing interaction (U) is to make motion of the bosons in the lattice correlated so as to avoid multiple occupancy of the sites. In the dilute limit, the e ect of U is not serious since there are enough vacant sites. The e ect of U then is prom inent when n is close to unity or to an integer value in the general case. In the large U limit, it becomes favorable for the bosons to localize on the sites to avoid the energy penalty of multiple site occupancy. Qualitatively then, one can see that increasing U increases the e ective mass (or decreases the band-width) of the bosons and eventually drives them, for integer lling, to a BMH insulator state. For large U, when the double or multiple occupancy is forbidden one can calculate the band-width reduction factor [B (n)] approximately following the spirit of Renormalized Hamiltonian Approach (RHA) to ferm ion Hubbard model^{27;28} based on Gutzwiller approximation $^{29;30}$. Within the RHA, the effect of projecting out double or multiple occupancies on a non-interacting boson wave function is taken into account by a a classical renormalization factor which is the ratio of the probabilities of the corresponding physical process in the projected and unprojected spaces. The probability of a hopping process in the projected space is given by n (1 n) for n 1. This simply implies that the site from which hopping takes place must be occupied and the target site must be empty in the projected space. In the unprojected space, the probability of hopping is just equal to the probability of the site from which hopping takes place being occupied. The hopping takes place for non-interacting bosons irrespective of the target site being empty or occupied by any number of bosons. This probability may be found out by calculating the number of ways a given number of non-interacting bosons is distributed in N $_{
m S}$ number of lattice sites and (N $_{
m S}$ number of lattice sites. The di erence would give the number of con gurations where a particular site is occupied. Following this route, the probability that a site is occupied is obtained as:

$$p(N;N_s) = 1 \frac{(N + N_s 2)!(N_s 1)!}{(N_s 2)!(N + N_s 1)!};$$
 (17)

where N and N $_{\rm s}$ are the total number of bosons and lattice sites, respectively. In the therm odynam ic lim it:

$$p(n) = \frac{n}{1+n}$$
: (18)

So, the hopping probability is just p(n). The above equation is valid for any n. Now, in the strongly correlated state (large U lim it), con ning to the case of n 1, the hopping probability is n (1 n). Hence the $_{\rm B}$ (n) is obtained to be,

$$_{B}$$
 (n) = 1 n^{2} : (19)

The above equation is valid only for n 1 and in the large U \lim it. It may be interesting for the reader to note that, in the Ferm ion case, $_F$ (n) = 2(1 n)=(2 n) which has been used in the studies 31 of superconductivity in strong coupling ferm ion Hubbard model of high tem perature superconductors. Since in the large U \lim it, double or higher site-occupancies are forbidden, one can write a renormalized Hamiltonian, valid for n 1, for strongly correlated bosons as:

$$H_{SC} = X_{[B](n)(k)} J_{k}^{Y} c_{k}$$
: (20)

The above H_{sc} is clearly the Hamiltonian of noninteracting bosons in a narrow band which has undergone a strong correlation induced lling-dependent bandnarrowing. One can see that as n increases from 0 to 1, the boson e ective mass increases to eventually diverge at n = 1 and a BMH insulator obtains. We do adm it that there are limitations to this renormalized Hamiltonian approach. W hile it has a merit that detailed band structure information can be incorporated in the Bose condensation tem perature calculation, it has the demerit that we have to restrict ourselves to large U and n The above Hamiltonian is valid for $U=W > (U=W)_{C}$ where $(U = W)_c$ is the critical value for transition into the M ott insulating phase for n = 1. Fixing a precise lower lim it on (U=W) is not possible in the absence of either exact analytical or num erical solution of three dim ensional Bose-Hubbard model. It may be mentioned that in this large U limit and for n 1, the Bose-Hubbard m odel is reduced to the lattice Tonks (hard-core boson) gas which is dierent from the classical gas of elastic hard spheres investigated by Tonks³². Our results im ply then that the e ective mass of bosons in a lattice Tonks gas in a narrow energy band is strongly band-lling dependent. The variation of bose condensation temperatures with n for bosons with correlation-induced renormalized energy bands corresponding to sc, bcc, and fcc lattices are displayed in Fig. (8). In the region between each curve and the n-axis, the bosons are in their bose-condensed state, and above each curve they are in their norm al state (except at n = 1 and below $k_B T$ U). The variation of T_B is a resultant of the combined e ects of increasing density and increasing e ective mass since TB is proportional to n=m . Beyond around twenty percent lling,

the increasing elective mass over-compensates the elect of increasing n and pulls down the growth of T_B eventually driving it to zero at n=1 at which density one has a BM H insulator.

It is of some interest to make a comparison between Mott-Hubbard (MH) metal-insulator transitions observed in ferm ion systems in condensed matterphysics. For a half- lled narrow band of ferm ions, one way to induce a M H insulator to metal transition is by reducing the ratio of Coulomb repulsion (U) to the band-width (2W). This was experimentally achieved³³ in V_2O_3 by application of pressure. This then is a band-width controlled M H transition 34 . A nother way to induce a M H insulator to metal transition is to start with a Mott insulator and reduce the band-lling which would then be lling-controlled M H transition. This was achieved 35 in $La_xSr_{1-x}TiO_3$. For a simple Gutzwiller approximation based analysis of the properties of this material see Ref. 36. Now, the Mott transition observed in boson system s in optical lattices is the band-width controlled one. It would be interesting to look for lling-controlled M ott transition in boson systems in optical lattices which may be possible by starting with the BMH insulator and ipping a few atom sout of the trap.

III. CONCLUSIONS

In this paper we presented a theoretical study of condensation of bosons in tight binding bands corresponding to sc, boc, and for lattices. We analyzed condensation temperature and condensate fraction of non-interacting bosons, weakly interacting bosons using Bogoliubov method, and strongly interacting bosons through a renormalized Hamiltonian approach (limited 1) capable of incorporating the detailed boson to n band structures. In all the cases studied, we nd that bosons in a tight binding band corresponding to a box lattice has the highest Bose condensation temperature. The growth of condensate fraction of non-interacting bosons is found to be very close to that of free bosons. In the case of weakly interacting bosons, the interaction partially depletes the condensate at zero temperature and close to it, while enhancing it beyond this range below the Bose-Einstein condensation temperature. Strong interaction enhances the boson e ective mass as the band-

lling is increased and eventually localizes them to form a Bose-M ott-H ubbard insulator for n=1. In the strongly interacting bosons case, we found that all bosons are in the condensate at absolute zero temperature. We also pointed out a possibility of a lling-controlled BM H transition for bosons in optical lattices.

ACKNOW LEDGM ENTS

We thank Prof. R.K.Moitra for many useful discussions. We also thank Prof. Bikas Chakrabarti for a useful discussion.

b on lien from SINP, Kolkata.

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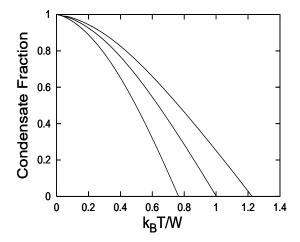


FIG.2. The same as in Fig. 1 for bosons in a bcc lattice for n = 0.8 (top), n = 0.6 (m iddle), n = 0.4 (bottom).

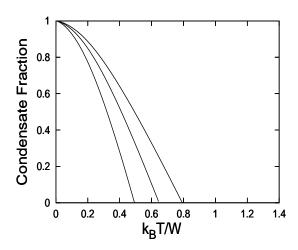


FIG. 1. The varation of condensate fraction with temperature for bosons in sc lattice for n=0.8 (top), n=0.6 (m iddle), n=0.4 (bottom). In this and other gures W is the half-band-width.

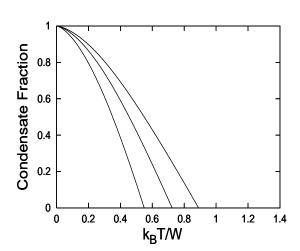


FIG.3. The same as in Fig. 1 for bosons in a fcc lattice for n = 0.8 (top), n = 0.6 (m iddle), n = 0.4 (bottom).

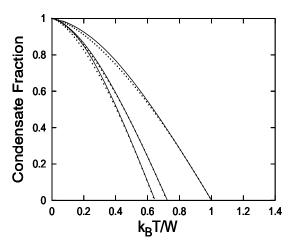


FIG .4. The variation of condensate fraction (for n = 0:6) for bcc (top), fcc (m iddle), and sc (bottom) lattices. The dots are plots of 1 $\,$ (T=T_c) $^{3+2}$.

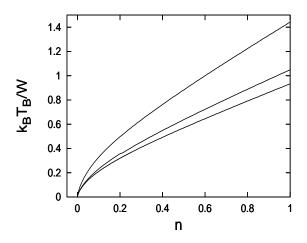


FIG.5. The variation of Bose condensation temperature (of non-interacting or weakly interacting bosons) with n for bcc (top), fcc (m iddle), and sc (bottom) lattices.

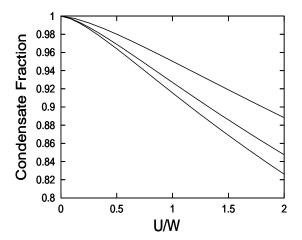


FIG.6. The variation of condensate fraction (for T = 0 and n = 0.4) with U=W for bcc (top), fcc (m iddle), and sc (bottom) lattices.

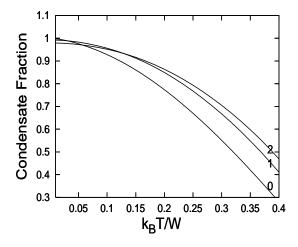


FIG .7. Condensate fraction (for n=0.4) vs tem perature for various values of U=W (shown on the curves) and for sc lattice.

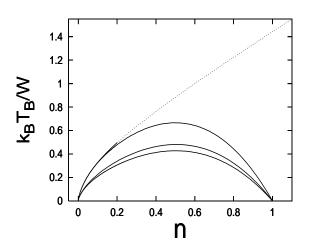


FIG. 8. Bose condensation temperature (of strongly interacting bosons) vs n for bcc (top), fcc (middle), and sc (bottom) lattices. The dots are for non-interacting bosons in a bcc lattice.